RoHS
Available on commercial versions

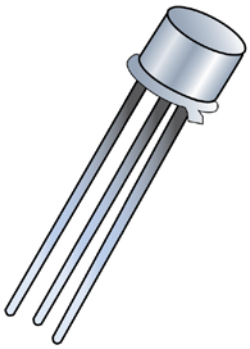
NPN SILICON TRANSISTOR
Qualified per MIL-PRF-19500/366

Qualified Levels:
JAN, JANTX, JANTXV and JANS

DESCRIPTION

This family of 2N3498 thru 2N3501 epitaxial planar transistors are military qualified up to a JANS level for high-reliability applications. These devices are also available in TO-5 and low profile U4 packaging. Microsemi also offers numerous other transistor products to meet higher and lower power ratings with various switching speed requirements in both through-hole and surface-mount packages.

Important: For the latest information, visit our website http://www.microsemi.com.



TO-39 (TO-205AD) Package

FEATURES

- JEDEC registered 2N3498 through 2N3501 series.
- JAN, JANTX, JANTXV, and JANS qualifications are available per MIL-PRF-19500/366. (See part nomenclature for all available options.)
- RoHS compliant versions available (commercial grade only).

Also available in:

TO-5 package
(long-leaded)
2N3498L – 2N3501L

U4 package
(surface mount)
2N3498U4 – 2N3501U4

APPLICATIONS / BENEFITS

- General purpose transistors for medium power applications requiring high frequency switching and low package profile.
- Military and other high-reliability applications.

MAXIMUM RATINGS

Parameters / Test Conditions	Symbol	2N3498 2N3499	2N3500 2N3501	Unit
Collector-Emitter Voltage	V_{CEO}	100	150	V
Collector-Base Voltage	V_{CBO}	100	150	V
Emitter-Base Voltage	V_{EBO}	6.0	6.0	V
Collector Current	I_C	500	300	mA
Thermal Resistance Junction-to-Ambient	$R_{\Theta JA}$	175		°C/W
Thermal Resistance Junction-to-Case	$R_{\Theta JC}$	30		°C/W
Total Power Dissipation @ T_A = +25 °C (1) @ T_C = +25 °C (2)	P_T	1.0 5.0		W
Operating & Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200		°C

Notes: 1. See figure 1.
2. See figure 2.

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MECHANICAL and PACKAGING

- CASE: Hermetically sealed, kovar base, nickel cap.
- TERMINALS: Leads are kovar, nickel plated, and finish is solder dip (Sn63/Pb37). Can be RoHS compliant with pure matte-tin (commercial grade only).
- MARKING: Part number, date code, manufacturer's ID.
- WEIGHT: Approximately 1.064 grams.
- See Package Dimensions on last page.

PART NOMENCLATURE

JAN 2N3498 (e3)

Reliability Level
JAN = JAN Level
JANTX = JANTX Level
JANTXV = JANTXV Level
JANS = JANS level
Blank = Commercial

JEDEC type number
(see Electrical Characteristics table)

RoHS Compliance
e3 = RoHS compliant (available on commercial grade only)
Blank = non-RoHS compliant

SYMBOLS & DEFINITIONS

Symbol	Definition
C_{obo}	Common-base open-circuit output capacitance
I_{CEO}	Collector cutoff current, base open
I_{CEX}	Collector cutoff current, circuit between base and emitter
I_{EBO}	Emitter cutoff current, collector open
h_{FE}	Common-emitter static forward current transfer ratio
V_{CEO}	Collector-emitter voltage, base open
V_{CBO}	Collector-emitter voltage, emitter open
V_{EBO}	Emitter-base voltage, collector open

ELECTRICAL CHARACTERISTICS @ T_A = +25 °C, unless otherwise noted

Characteristic		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage					
I_C = 10 mA, pulsed	2N3498, 2N3499	$V_{(BR)CEO}$	100		V
	2N3500, 2N3501		150		
Collector-Base Cutoff Current					
V_{CB} = 50 V	2N3498, 2N3499	I_{CBO}		50	nA
V_{CB} = 75 V	2N3500, 2N3501			50	nA
V_{CB} = 100 V	2N3498, 2N3499			10	µA
V_{CB} = 150 V	2N3500, 2N3501			10	µA
Emitter-Base Cutoff Current					
V_{EB} = 4.0 V		I_{EBO}		25	nA
V_{EB} = 6.0 V				10	µA
ON CHARACTERISTICS (1)					
Forward-Current Transfer Ratio					
I_C = 0.1 mA, V_{CE} = 10 V	2N3498, 2N3500	h_{FE}	20		
	2N3499, 2N3501		35		
I_C = 1.0 mA, V_{CE} = 10 V	2N3498, 2N3500		25		
	2N3499, 2N3501		50		
I_C = 10 mA, V_{CE} = 10 V	2N3498, 2N3500		35		
	2N3499, 2N3501		75		
I_C = 150 mA, V_{CE} = 10 V	2N3498, 2N3500		40	120	
	2N3499, 2N3501		100	300	
I_C = 300 mA, V_{CE} = 10 V	2N3500		15		
	2N3501		20		
I_C = 500 mA, V_{CE} = 10 V	2N3498		15		
	2N3499		20		
Collector-Emitter Saturation Voltage					
I_C = 10 mA, I_B = 1.0 mA	All Types	$V_{CE(sat)}$		0.2	V
I_C = 300 mA, I_B = 30 mA	2N3498, 2N3499			0.6	
I_C = 150 mA, I_B = 15 mA	2N3500, 2N3501			0.4	
Base-Emitter Saturation Voltage					
I_C = 10 mA, I_B = 1.0 mA	All Types	$V_{BE(sat)}$		0.8	V
I_C = 300 mA, I_B = 30 mA	2N3498, 2N3499			1.4	
I_C = 150 mA, I_B = 15 mA	2N3500, 2N3501			1.2	
DYNAMIC CHARACTERISTICS					
Forward Current Transfer Ratio, Magnitude					
I_C = 20 mA, V_{CE} = 20 V, f = 100 MHz		$\|h_{fe}\|$	1.5	8.0	
Output Capacitance					
V_{CB} = 10 V, I_E = 0,	2N3498, 2N3499	C_{obo}		10	pF
100 kHz ≤ f ≤ 1.0 MHz	2N3500, 2N3501			8.0	
Input Capacitance					
V_{EB} = 0.5 V, I_C = 0, 100 kHz ≤ f ≤ 1.0 MHz		C_{ibo}		80	pF

(1) Pulse Test: pulse width = 300 µs, duty cycle ≤ 2.0%.

ELECTRICAL CHARACTERISTICS @ T_A = +25 °C, unless otherwise noted

SWITCHING CHARACTERISTICS

Characteristic	Symbol	Min.	Max.	Unit
Turn-On Time V_{EB} = 5 V; I_C = 150 mA; I_{B1} = 15 mA	t_{on}		115	ns
Turn-Off Time I_C = 150 mA; I_{B1} = I_{B2} = -15 mA	t_{off}		1150	ns

SAFE OPERATING AREA (See SOA figure and reference MIL-STD-750 method 3053)

DC Tests

T_C = +25 °C, $t_r \geq$ 10 ns; 1 Cycle, t = 1.0 s

Test 1

V_{CE} = 10 V, I_C = 500 mA	2N3498, 2N3499
V_{CE} = 16.67 V, I_C = 300 mA	2N3500, 2N3501

Test 2

V_{CE} = 50 V, I_C = 100 mA	All Types

Test 3

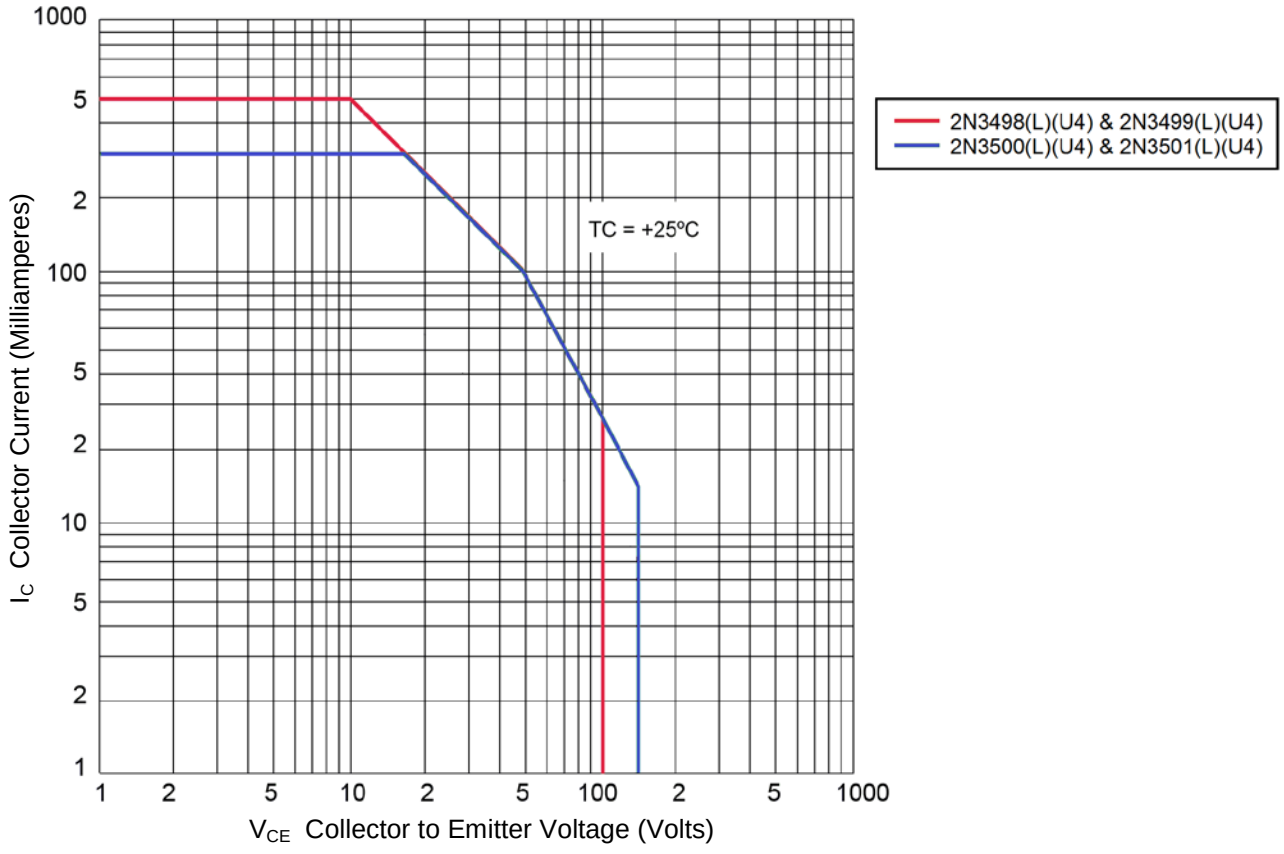
V_{CE} = 80 V, I_C = 40 mA	All Types

Clamped Switching

T_A = +25 °C

Test 1

I_B = 85 mA, I_C = 500 mA	2N3498, 2N3499
I_B = 50 mA, I_C = 300 mA	2N3500, 2N3501



Maximum Safe Operating Area

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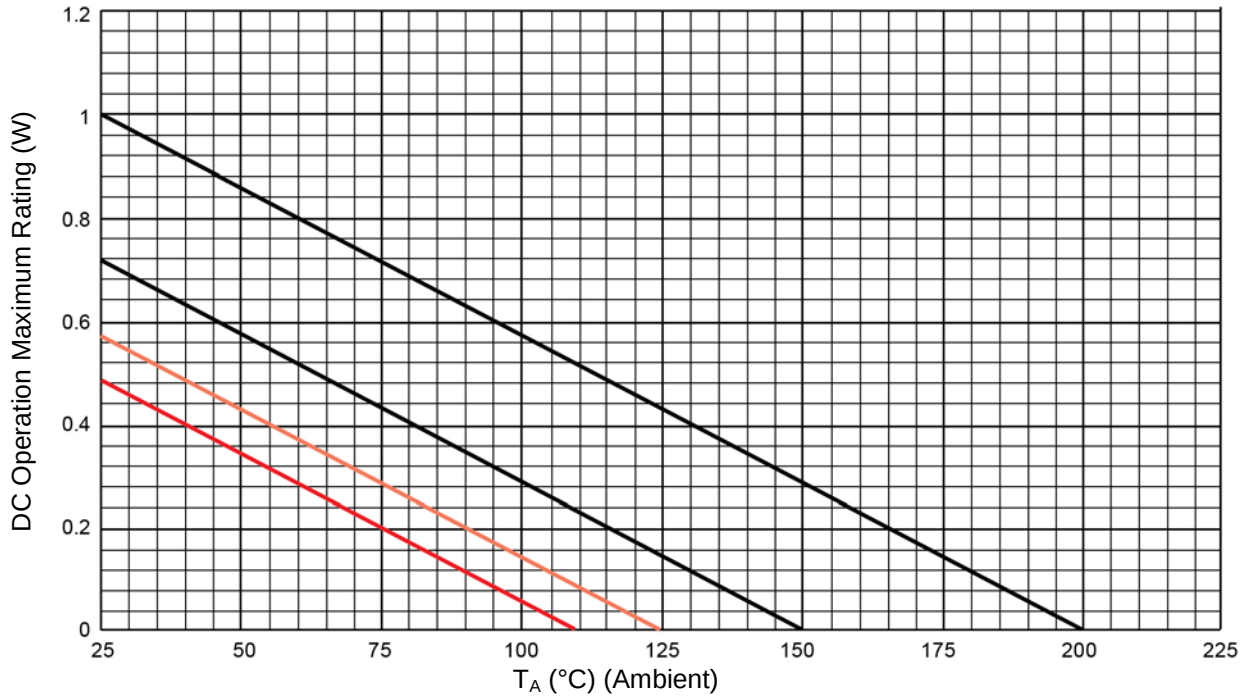

FIGURE 1

Derating for all devices ($R_{\theta JA}$)

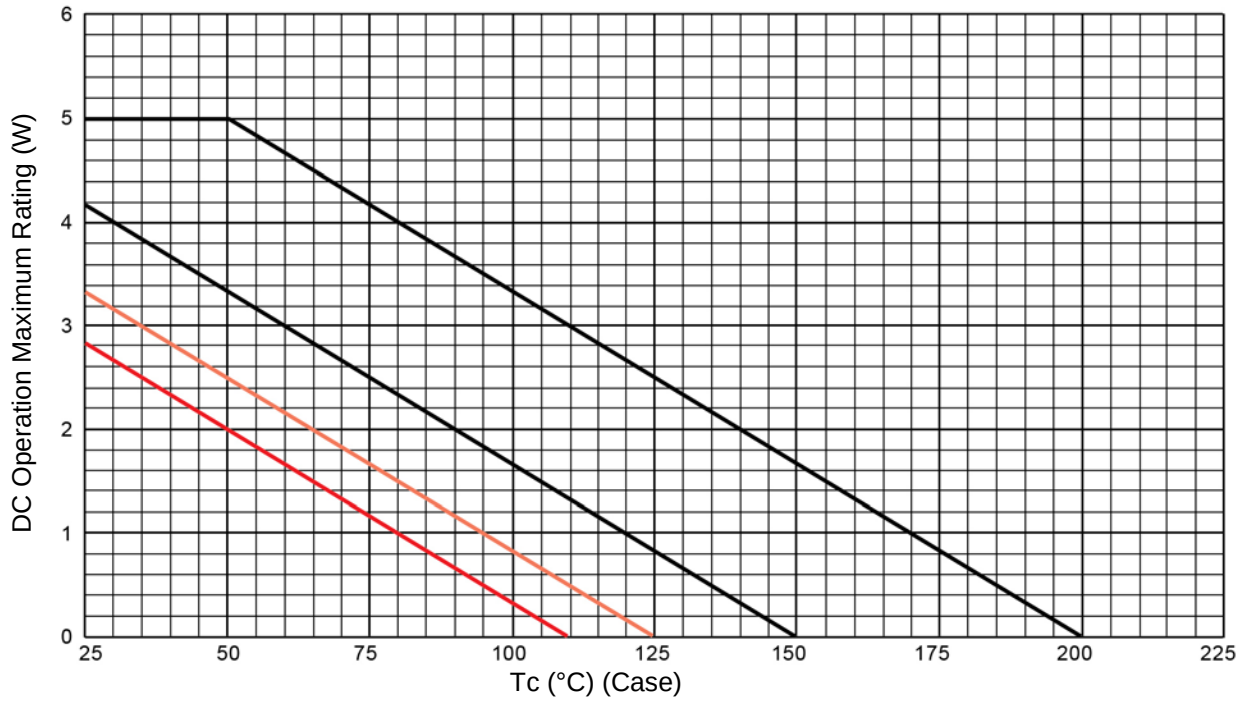

FIGURE 2

Derating for all devices ($R_{\theta JC}$)

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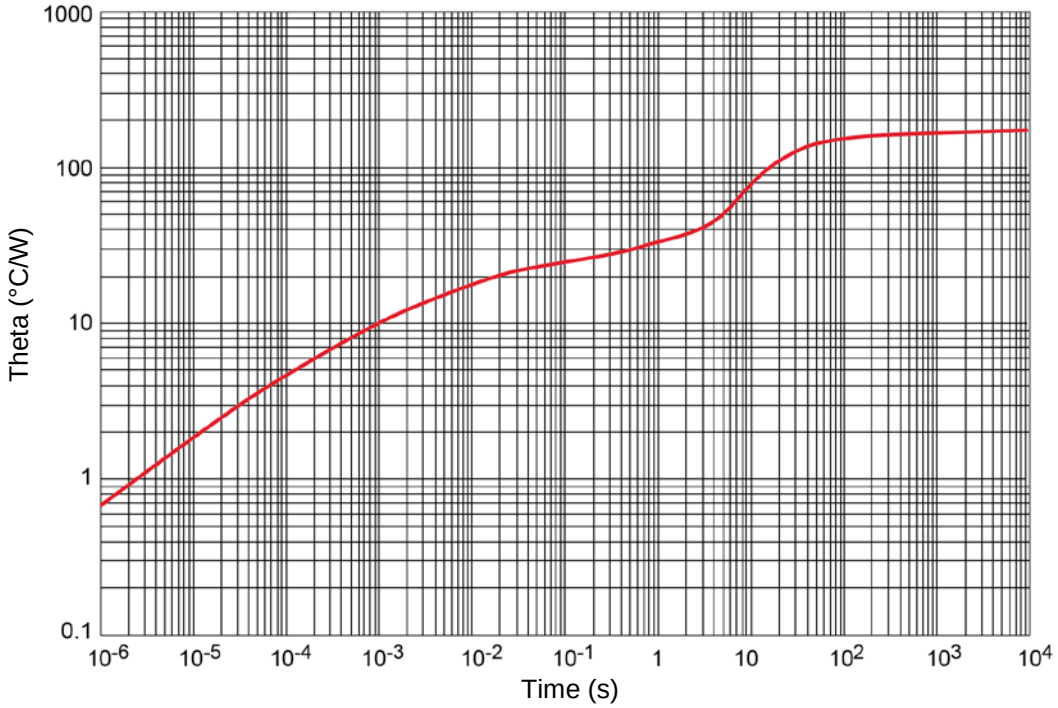


FIGURE 3

Thermal Impedance Graph ($R_{\theta JA}$)

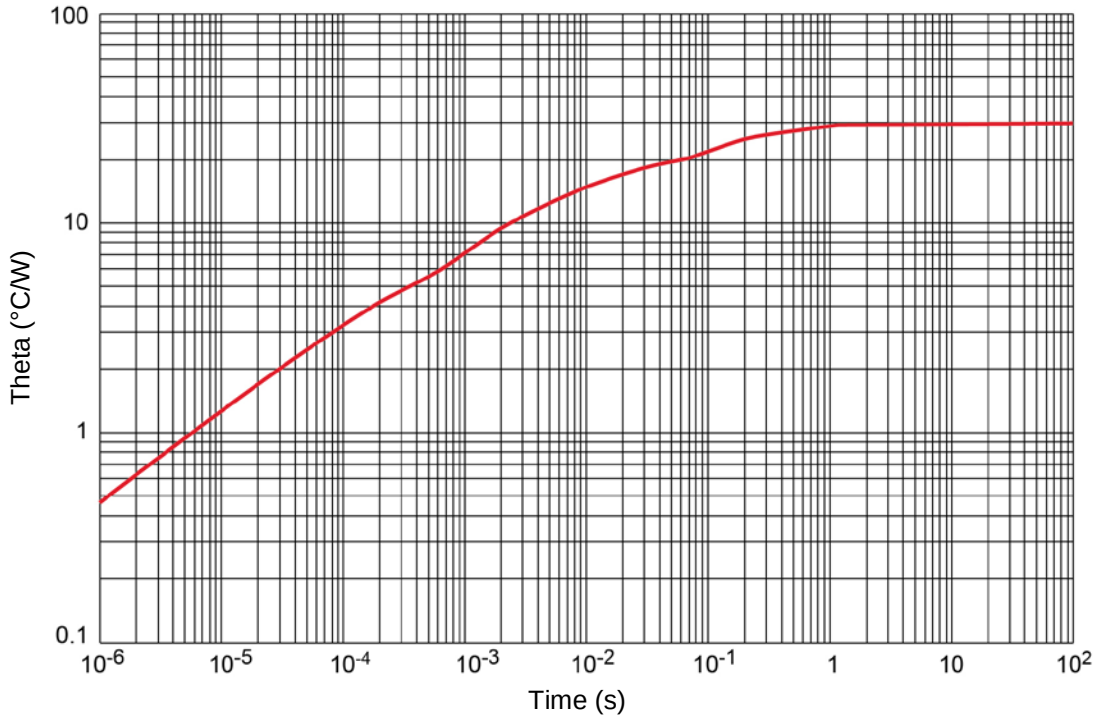
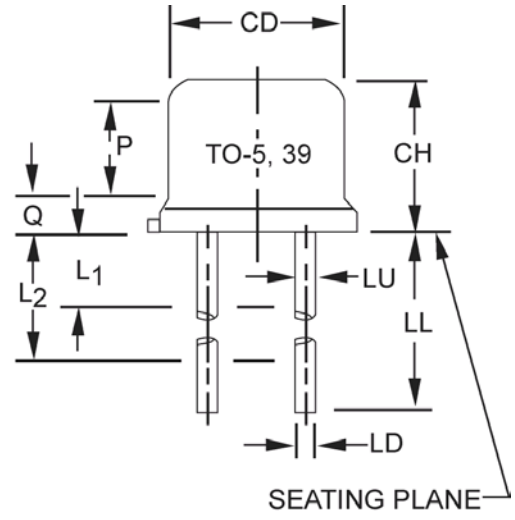
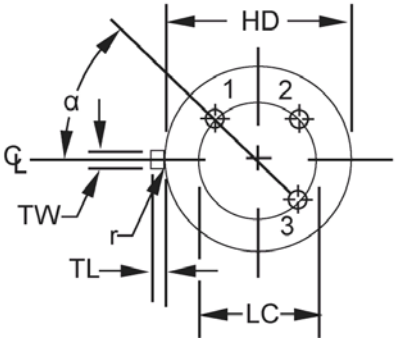


FIGURE 4

Thermal Impedance Graph ($R_{\theta JC}$)

PACKAGE DIMENSIONS





Symbol	Dimensions				Note
	Inch		Millimeters		
	Min	Max	Min	Max	
CD	0.305	0.335	7.75	8.51	
CH	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC	0.200 TP		5.08 TP		6
LD	0.016	0.021	0.41	0.53	7
LL	See notes 7, 12 and 13				
LU	0.016	0.019	0.41	0.48	7, 13
L1		0.050		1.27	13
L2	0.250		6.35		13
P	0.100		2.54		5
Q		0.050		1.27	4
TL	0.029	0.045	0.74	1.14	3
TW	0.028	0.034	0.71	0.86	10, 11
r		0.010		0.25	11
α	45° TP		45° TP		6

NOTES:

1. Dimension are in inches.
2. Millimeters are given for general information only.
3. Symbol TL is measured from HD maximum.
4. Details of outline in this zone are optional.
5. Symbol CD shall not vary more than .010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
6. Leads at gauge plane .054 inch (1.37 mm) +.001 inch (0.03 mm) -.000 inch (0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) relative to tab. Device may be measured by direct methods or by gauge.
7. Symbol LD applies between L1 and L2. Dimension LD applies between L2 and LL minimum. Lead diameter shall not exceed .042 inch (1.07 mm) within L1 and beyond LL minimum.
8. Lead designation, shall be as follows: 1 - emitter, 2 - base, 3 - collector.
9. Lead number three is electrically connected to case.
10. Beyond r maximum, TW shall be held for a minimum length of .011 inch (0.28 mm).
11. Symbol r applied to both inside corners of tab.
12. For transistor types 2N3498, 2N3499, 2N3500, and 2N3501, LL = .50 inch (12.7 mm) minimum and .750 inch (19.1 mm) maximum. For transistor types 2N3498L, 2N3499L, 2N3500L, and 2N3501L, LL = 1.50 inches (38.1 mm) minimum and 1.750 inches (44.5 mm) maximum.
13. All three leads.
14. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

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